NSN 5962-01-386-3200

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating: 1.04 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and programmed **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Case Outline Source And Designator:** D-3 mil-m-38510 **Current Rating Per Characteristic:** 190.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 100.00 nanoseconds delay Memory Device Type: Prom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit Shelf Life: Unit Of Measure: **Demilitarization:** Yes - demil/mli Fiig: A458a0

N/a

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